DISCRETE SEMICONDUCTORS



Product specification Supersedes data of April 1995 File under Discrete Semiconductors, SC07 1996 Jul 30



Philips Semiconductors

J108; J109; J110

FEATURES

- High speed switching
- · Interchangeability of drain and source connections
- Low R_{DSon} at zero gate voltage (<8 Ω for J108).

APPLICATIONS

- · Analog switches
- Choppers and commutators.

DESCRIPTION

N-channel symmetrical silicon junction field-effect transistors in a TO-92 package.

CAUTION

The device is supplied in an antistatic package. The gate-source input must be protected against static discharge during transport or handling.

QUICK REFERENCE DATA

PINNING - TO-92

PIN	SYMBOL	DESCRIPTION
1	g	gate
2	S	source
3	d	drain



SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V _{DS}	drain-source voltage		_	±25	V
V _{GSoff}	gate-source cut-off voltage	$I_{D} = 1 \ \mu A; \ V_{DS} = 5 \ V$			
	J108		-3	-10	V
	J109		-2	-6	V
	J110		-0.5	-4	V
I _{DSS}	drain current	$V_{GS} = 0; V_{DS} = 5 V$			
	J108		80	_	mA
	J109		40	_	mA
	J110		10	_	mA
P _{tot}	total power dissipation	up to T _{amb} = 50 °C	_	400	mW

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LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V _{DS}	drain-source voltage		-	±25	V
V _{GSO}	gate-source voltage	open drain	-	-25	V
V _{GDO}	gate-drain voltage	open source	-	-25	V
I _G	forward gate current (DC)		-	50	mA
P _{tot}	total power dissipation	up to $T_{amb} = 50 \ ^{\circ}C$	-	400	mW
T _{stg}	storage temperature		-65	150	°C
Tj	operating junction temperature		_	150	°C

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	VALUE	UNIT
R _{th j-a}	thermal resistance from junction to ambient	250	K/W

STATIC CHARACTERISTICS

 $T_i = 25 \ ^{\circ}C$; unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
V _{(BR)GSS}	gate-source breakdown voltage	$I_{G} = -1 \ \mu A; V_{DS} = 0$	_	-	-25	V
V _{GSoff}	gate-source cut-off voltage	I _D = 1 μA; V _{DS} = 5 V				V
	J108		-3	_	-10	V
	J109		-2	_	-6	V
	J110		-0.5	_	-4	V
I _{DSS}	drain current	V _{GS} = 0; V _{DS} = 15 V				
	J108		80	_	_	mA
	J109		40	_	_	mA
	J110		10	_	_	mA
I _{GSS}	gate leakage current	$V_{GS} = -15 \text{ V}; V_{DS} = 0$	_	_	-3	nA
I _{DSX}	drain-source cut-off current	$V_{GS} = -10 \text{ V}; \text{ V}_{DS} = 5 \text{ V}$	_	_	3	nA
R _{DSon}	drain-source on-state resistance	V _{GS} = 0; V _{DS} = 100 mV				
	J108		_	_	8	Ω
	J109		-	_	12	Ω
	J110		-	_	18	Ω

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DYNAMIC CHARACTERISTICS

 $T_i = 25 \ ^{\circ}C$; unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	TYP.	MAX.	UNIT
C _{is}	input capacitance	$V_{DS} = 0; V_{GS} = -10 V; f = 1 MHz$	15	30	pF
		V_{DS} = 0; V_{GS} = 0; f = 1 MHz; T_{amb} = 25 °C	50	85	pF
C _{rs}	reverse transfer capacitance	$V_{DS} = 0; V_{GS} = -10 V; f = 1 MHz$	8	15	pF
Switching ti	mes; see Fig.2				
t _d	delay time	note 1	2	-	ns
t _{on}	turn-on time		4	-	ns
t _s	storage time		4	-	ns
t _{off}	turn-off time		6	-	ns

Note

1. Test conditions for switching times are as follows:

 V_{DD} = 1.5 V; V_{GS} = 0 to V_{GSoff} (all types)

 V_{GSoff} = –12 V; R_L = 100 Ω (J108)

 V_{GSoff} = -7 V; R_L = 100 Ω (J109)

 V_{GSoff} = –5 V; R_L = 100 Ω (J110).



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PACKAGE OUTLINE



Product specification

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DEFINITIONS

Data Sheet Status		
Objective specification This data sheet contains target or goal specifications for product development.		
Preliminary specification	This data sheet contains preliminary data; supplementary data may be published later.	
Product specification	This data sheet contains final product specifications.	
Limiting values		
more of the limiting values m of the device at these or at a	accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or nay cause permanent damage to the device. These are stress ratings only and operation any other conditions above those given in the Characteristics sections of the specification imiting values for extended periods may affect device reliability.	

Application information

Where application information is given, it is advisory and does not form part of the specification.

LIFE SUPPORT APPLICATIONS

These products are not designed for use in life support appliances, devices, or systems where malfunction of these products can reasonably be expected to result in personal injury. Philips customers using or selling these products for use in such applications do so at their own risk and agree to fully indemnify Philips for any damages resulting from such improper use or sale.